

# **2SJ217** Silicon P Channel MOS FET

REJ03G0850-0200 (Previous: NON-084) Rev.2.00 Sep 07, 2005

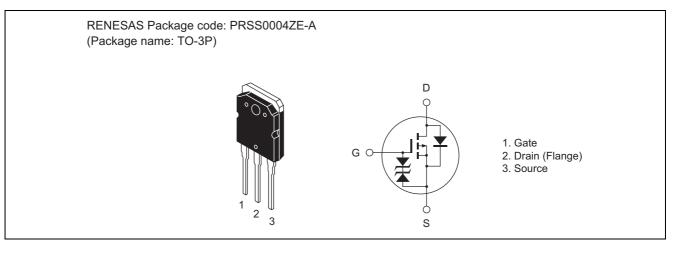
### Description

High speed power switching

### Features

- Low on-resistance
- High speed switching
- Low drive current
- 4 V gate drive device
  - Can be driven from 5 V source
- Suitable for motor drive, DC-DC converter, power switch and solenoid drive

### Outline





# Absolute Maximum Ratings

(Ta = 25)	°C)
-----------	-----

Item	Symbol	Value	Unit
Drain to source voltage	V <sub>DSS</sub>	-60	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	ID	-45	A
Drain peak current	I <sub>D (pulse)</sub> Note 1	-180	A
Body to drain diode reverse drain current	I <sub>DR</sub>	-45	A
Channel dissipation	Pch Note 2	150	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at Tc =  $25^{\circ}C$ 

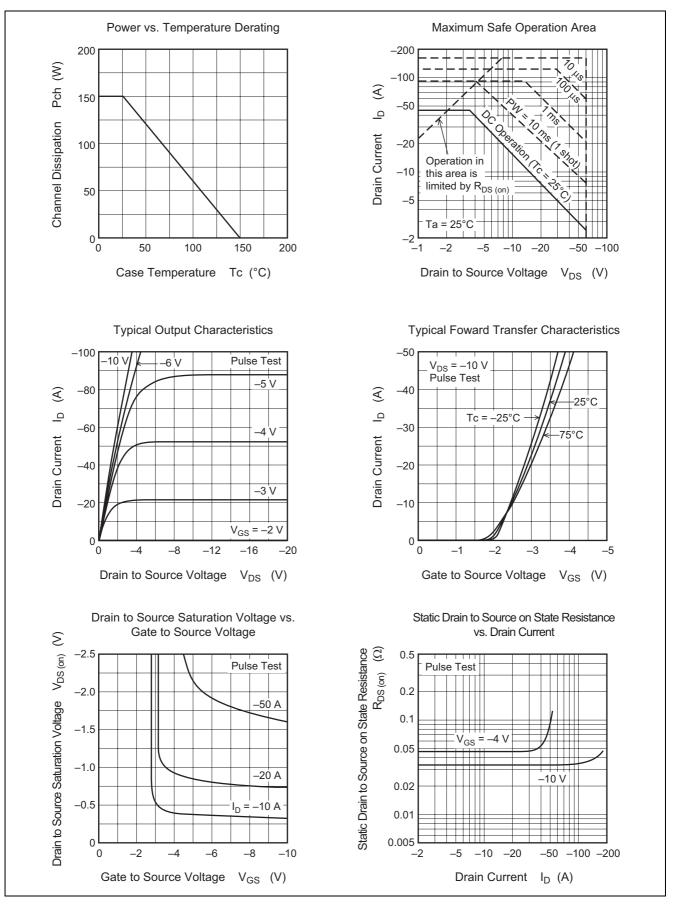
# **Electrical Characteristics**

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V (BR) DSS	-60			V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V (BR) GSS	±20	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_		±10	μA	$V_{GS} = \pm 16 \text{ V},  V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_		-250	μA	$V_{DS} = -50 \text{ V}, \text{ V}_{GS} = 0$
Gate to source cutoff voltage	V <sub>GS (off)</sub>	-1.0		-2.0	V	$I_D = -1 \text{ mA}, V_{DS} = -10 \text{ V}$
Static drain to source on state resistance	R <sub>DS (on)</sub>	_	0.033	0.042	Ω	$I_D = -20 \text{ A}, \text{ V}_{GS} = -10 \text{ V}^{\text{Note 3}}$
	R <sub>DS (on)</sub>	_	0.045	0.06	Ω	$I_D = -20 \text{ A}, \text{ V}_{GS} = -4 \text{ V}^{\text{Note 3}}$
Forward transfer admittance	y <sub>fs</sub>	16	25	_	S	$I_D = -20 \text{ A}, V_{DS} = -10 \text{ V}^{Note 3}$
Input capacitance	Ciss	_	3800	_	pF	$V_{DS} = -10 V$
Output capacitance	Coss	_	2000	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	490	_	pF	f = 1 MHz
Turn-on delay time	t <sub>d (on)</sub>	_	30	_	ns	I <sub>D</sub> = -20 A
Rise time	t <sub>r</sub>	_	235	_	ns	$V_{GS} = -10 V$
Turn-off delay time	t <sub>d (off)</sub>	_	670	_	ns	$R_L = 1.5 \Omega$
Fall time	t <sub>f</sub>	_	450		ns	
Body to drain diode forward voltage	V <sub>DF</sub>	_	-1.35		V	$I_F = -45 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery time	t <sub>rr</sub>	_	300		ns	$I_F = -45 \text{ A}, V_{GS} = 0$
						di <sub>F</sub> /dt = 50 A/μs

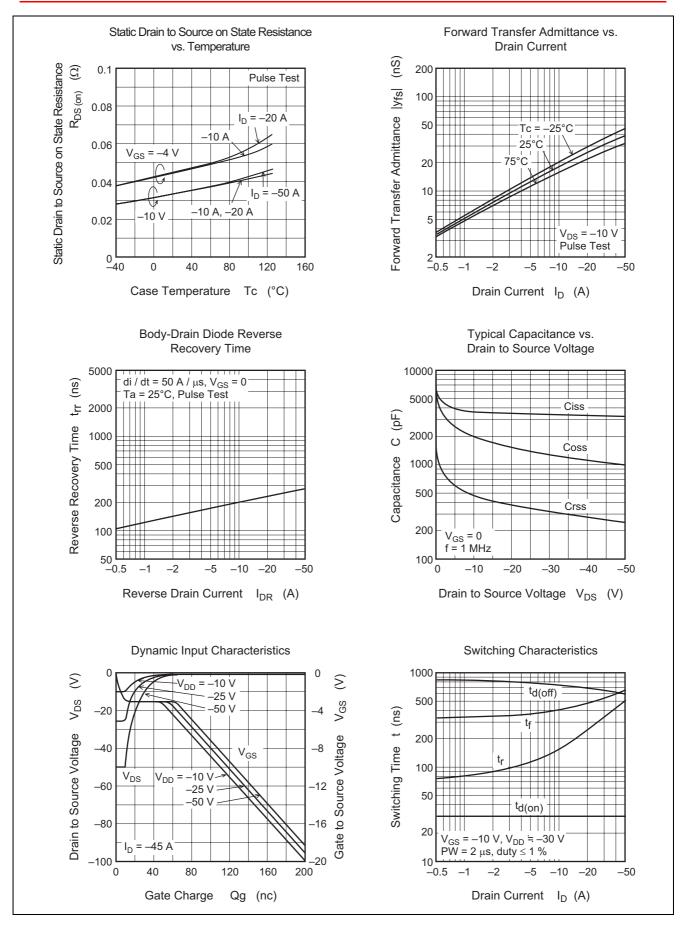
Note: 3. Pulse test



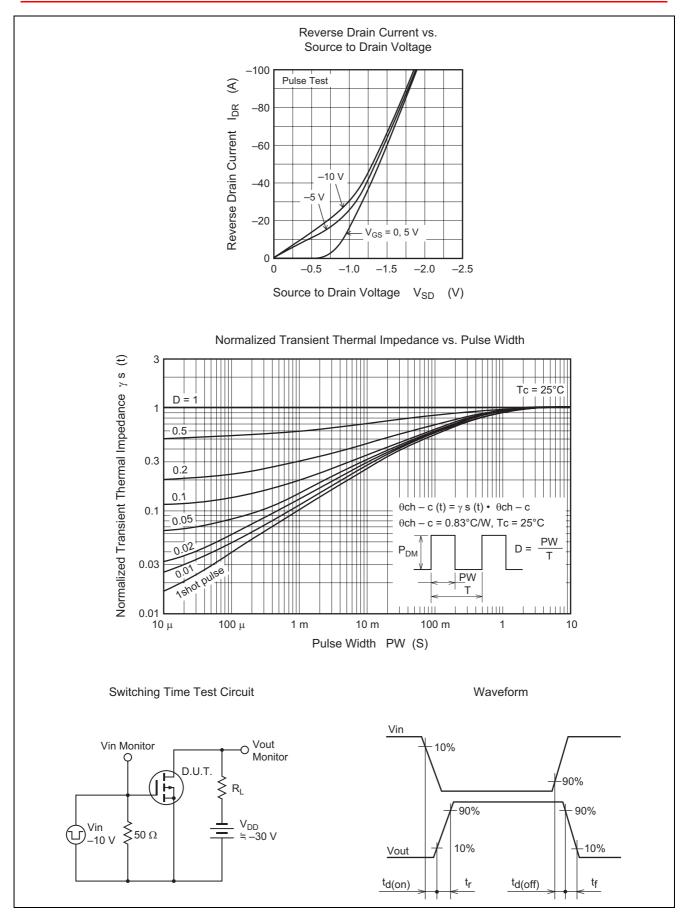
### **Main Characteristics**





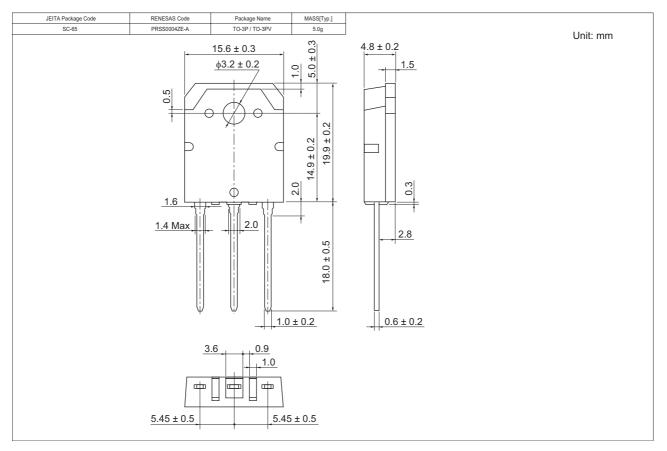


RENESAS





## **Package Dimensions**



### **Ordering Information**

Part Name	Quantity	Shipping Container
2SJ217-E	30 pcs	Plastic magazine

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



# Renesas Technology Corp. sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

Keep safety first in your circuit designs! 1. Renesas Technology Corp. puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of nonflammable material or (iii) prevention against any malfunction or mishap.

### Notes regarding these materials

- Notes regarding these materials
   These materials are intended as a reference to assist our customers in the selection of the Renesas Technology Corp. product best suited to the customer's application; they do not convey any license under any intellectual property rights, or any other rights, belonging to Renesas Technology Corp. or a third party.
   Renesas Technology Corp. assumes no responsibility for any damage, or infringement of any third-party's rights, originating in the use of any product data, diagrams, charts, programs, algorithms, or circuit application examples contained in these materials.
   All information contained in these materials, including product data, diagrams, charts, programs and algorithms represents information on products at the time of publication of these materials, and are subject to change by Renesas Technology Corp. vithout notice due to product improvements or other reasons. It is therefore recommended that customers contact Renesas Technology Corp. or an authorized Renesas Technology Corp. product distributor for the latest product information before purchasing a product listed herein.
   The information described here may contain technical inaccuracies or typographical errors. Renesas Technology Corp. assumes no responsibility for any damage, liability, or other loss rising from these inaccuracies or errors. Please also pay attention to information published by Renesas Technology Corp. by various means, including the Renesas Technology Corp. Semiconductor home page (http://www.renesas.com).
   When using any or all of the information contained in these materials. including product data, diagrams, charts, programs, and algorithms, please be sure to

- Nome page (ntp://www.renesas.com).
  4. When using any or all of the information contained in these materials, including product data, diagrams, charts, programs, and algorithms, please be sure to evaluate all information as a total system before making a final decision on the applicability of the information and products. Renesas Technology Corp. assumes no responsibility for any damage, liability or other loss resulting from the information contained herein.
  5. Renesas Technology Corp. semiconductors are not designed or manufactured for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contact Renesas Technology Corp. or an authorized Renesas Technology Corp. product distributor when considering the use of a product contained herein for any specific purposes, such as apparatus or systems for transportation, vehicular, medical, aerospace, nuclear, or undersea repeater use.
- use. 6. The prior written approval of Renesas Technology Corp. is necessary to reprint or reproduce in whole or in part these materials. 7. If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination. Any diversion or reexport contrary to the export control laws and regulations of Japan and/or the country of destination is prohibited. 8. Please contact Renesas Technology Corp. for further details on these materials or the products contained therein.



### **RENESAS SALES OFFICES**

Refer to "http://www.renesas.com/en/network" for the latest and detailed information.

Renesas Technology America, Inc. 450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K. Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology Hong Kong Ltd.

7th Floor, North Tower, World Finance Centre, Harbour City, 1 Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2730-6071

Renesas Technology Taiwan Co., Ltd. 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology (Shanghai) Co., Ltd. Unit2607 Ruijing Building, No.205 Maoming Road (S), Shanghai 200020, China Tel: <86> (21) 6472-1001, Fax: <86> (21) 6415-2952

### Renesas Technology Singapore Pte. Ltd.

1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> 2-796-3115, Fax: <82> 2-796-2145

### Renesas Technology Malaysia Sdn. Bhd.

Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510

© 2005. Renesas Technology Corp., All rights reserved. Printed in Japan. Colophon .3.0

http://www.renesas.com